NB3N508S

3.3V, 216 MHz PureEdge VCXO Clock Generator with M-LVDS Output

ON Semiconductor®

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Description

The NB3N508S is a high precision, low phase noise Voltage Controlled Crystal Oscillator (VCXO) and phase lock loop (PLL) that generates 216 MHz M−LVDS output from a 27 MHz crystal. The ±100 ppm output pullable range is obtained using the V_{IN} pin of the VCXO with usable range from 0 V to 3.3 V. The VCXO input pin V_{IN} is a high−impedance input that can be driven directly from a pulse width modulated RC integrator circuit.

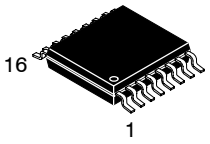
The NB3N508S is designed primarily for data and clock recovery applications within end products such as ADSL modems, set−top box receivers, and telecom systems. This device is housed in 5.0 mm x 4.4 mm narrow body TSSOP−16 pin package.

Features

- PureEdge Clock Family Provides Accuracy and Precision
- Performs Precision Clock Multiplication from 27 MHz Crystal
- Uses 27 MHz Fundamental Mode Crystal
- External Loop Filter is Not Required
- 216 MHz M−LVDS Output
- VCXO with Pull Range ±100 ppm
- 0 V to 3.3 V VCXO Tuning Voltage Range Capabilities
- Phase Noise:

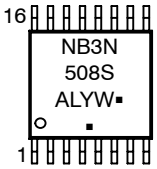
Offset	Noise Power
100 Hz	−80 dBc
1 kHz	−88 dBc
10 kHz	−105 dBc
100 kHz	−106 dBc
1 MHz	−120 dBc
10 MHz	−145 dBc

- Operating Range 3.3 V ±5%
- These are Pb−Free Devices*



TSSOP−16
DT SUFFIX
CASE 948F

MARKING DIAGRAM



A	= Assembly Location
L	= Wafer Lot
Y	= Year
W	= Work Week
▪	= Pb−Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 7 of this data sheet.

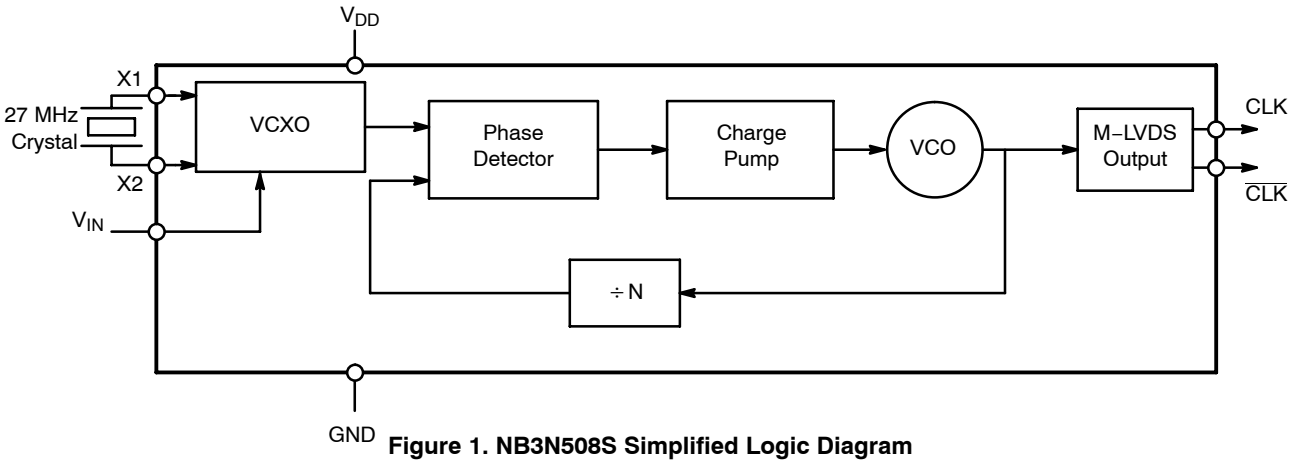


Figure 1. NB3N508S Simplified Logic Diagram

*For additional information on our Pb−Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

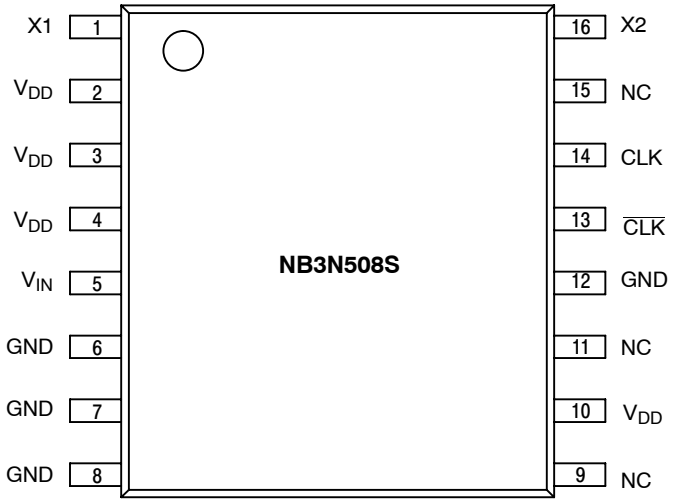


Figure 2. Pin Configuration (Top View)

Table 1. PIN DESCRIPTION

Pin	Name	I/O	Description
1	X1	Crystal Input	Crystal input(IN). Connect to a 27 MHz crystal.
2, 3, 4, 10	V_{DD}	Power Supply	Positive power supply voltage.
5	V_{IN}	Input	Analog voltage input pin that controls output oscillation frequencies. V_{IN} pin range is from 0 V to 3.3 V. V_{IN} voltage should not exceed V_{DD}.
6, 7, 8, 12	GND	Power Supply	Ground 0 V. These pins provide GND return path for the devices.
9, 11, 15	NC	–	No Connect.
13	$\overline{CLK}$	M−LVDS Output	Inverted clock output. Typically loaded with 50 Ω receiver termination resistor across diff. pair.
14	CLK	M−LVDS Output	Noninverted clock output. Typically loaded with 50 Ω receiver termination resistor across diff. pair.
16	X2	Crystal Input	Crystal input(OUT). Connect to a 27 MHz crystal.

Recommended Crystal Parameters

Crystal Fundamental AT−Cut Frequency	27 MHz
Load Capacitance	14 pF
Shunt Capacitance, C0	7 pF
Max Equivalent Series Resistance	35 Ω
Max Initial Accuracy at 25°C	±20 ppm
Temperature Stability	±30 ppm
Aging	±20 ppm
C0/C1 Ration	250 Max

Table 2. ATTRIBUTES

Characteristics		Value
ESD Protection	Human Body Model Machine Model	> 4 kV > 400 V
Moisture Sensitivity, Indefinite Time Out of Drypack (Note 1)	TSSOP−16	Level 3
Flammability Rating	Oxygen Index: 28 to 34	UL 94 V−0 @ 0.125 in
Transistor Count		6000 Devices
Meets or exceeds JEDEC Spec EIA/JESD78 IC Latchup Test		

1. For additional information, see Application Note AND8003/D.

Table 3. MAXIMUM RATINGS

Symbol	Parameter	Condition 1	Condition 2	Rating	Unit
V_{DD}	Positive Power Supply	GND = 0 V		4.6	V
V_I	Input Voltage (V_{IN})	GND = 0 V	$GND \le V_I \le V_{DD}$	V_{DD}	V
I_{OUT}	M−LVDS Output Current	Continuous Surge		25 50	mA mA
T_A	Operating Temperature Range			0 to +70	°C
T_{STG}	Storage Temperature Range			−65 to +150	°C
θ_{JA}	Thermal Resistance (Junction−to−Ambient)	0 lfpm 500 lfpm	TSSOP−16 TSSOP−16	138 108	°C/W °C/W
θ_{JA}	Thermal Resistance (Junction−to−Case)	(Note 2)	TSSOP−16	33 to 36	°C/W
T_{SOL}	Wave Solder Pb−Free			265	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

2. JEDEC standard multilayer board − 2S2P (2 Signal, 2 Power).

Table 4. DC CHARACTERISTICS (V_{DD} = 3.135 V to 3.465 V, GND = 0 V, T_A = 0°C to +70°C)

Symbol	Characteristic	Min	Typ	Max	Unit
I_{DD}	Power Supply Current (outputs loaded with R_L = 50 Ω)	42	52	62	mA
V_{IA}	VCXO Control Voltage, V_{IN}	0		3.3	V
V_{OD}	Differential Output Voltage (Note 3)	480	565	650	mV
ΔV_{OD}	Change in Magnitude of V_{OD} for Complementary Output States (Notes 3, 6)	−50		50	mV
V_{OS}	Offset Voltage (See Figure 4)	300		2100	mV
ΔV_{OS}	Change in Magnitude of V_{OS} for Complementary Output States (Note 6)	−50		50	mV
V_{OH}	Output HIGH Voltage (Note 4)		1300	2425	mV
V_{OL}	Output LOW Voltage (Note 5)	−25	700		mV
I_{SC}	Output Short Circuit Current CLK or $\overline{CLK}$ to GND			43	mA

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

3. M−LVDS outputs require 50 Ω receiver termination resistor between differential. pair. See Figure 3
4. $V_{OHmax} = V_{OSmax} + ½ V_{ODmax}$.
5. $V_{OLmax} = V_{OSmin} − ½ V_{ODmax}$.
6. Parameters guaranteed by design but not tested in production.

Table 5. AC CHARACTERISTICS (V_{DD} = 3.135 V to 3.465 V, GND = 0 V, T_A = 0°C to +70°C, Note 7)

Symbol	Characteristic	Min	Typ	Max	Unit
f_{CLKIN}	Crystal Input Frequency		27		MHz
f_{CLKOUT}	Output Clock Frequency		216		MHz
Φ_{NOISE}	Phase−Noise Performance f_{CLKOUT} = 216 MHz @ 100 Hz Offset from Carrier @ 1 kHz Offset from Carrier @ 10 kHz Offset from Carrier @ 100 kHz Offset from Carrier @ 1 MHz Offset from Carrier @ 10 MHz Offset from Carrier		 −80 −88 −105 −106 −120 −145		dBc/Hz
	Spurious Noise Components		−60		dBc/Hz
F_P	Crystal Pullability 0 V ≤ V_{IN} ≤ 3.3 V	±100			ppm
t_{DUTY_CYCLE}	Output Clock Duty Cycle (Measured at Crosspoint)	45	50	55	%
t_R	Output Rise Time (CLK/$\overline{CLK}$) (Note 8)		380	500	ps
t_F	Output Fall Time (CLK/$\overline{CLK}$) (Note 8)		380	500	ps

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

7. CLK/$\overline{CLK}$ loaded with 50 Ω receiver termination resistor between diff. pair.
8. Measured differentially (CLK − $\overline{CLK}$) at 10% to 90%; R_L = 50 Ω.

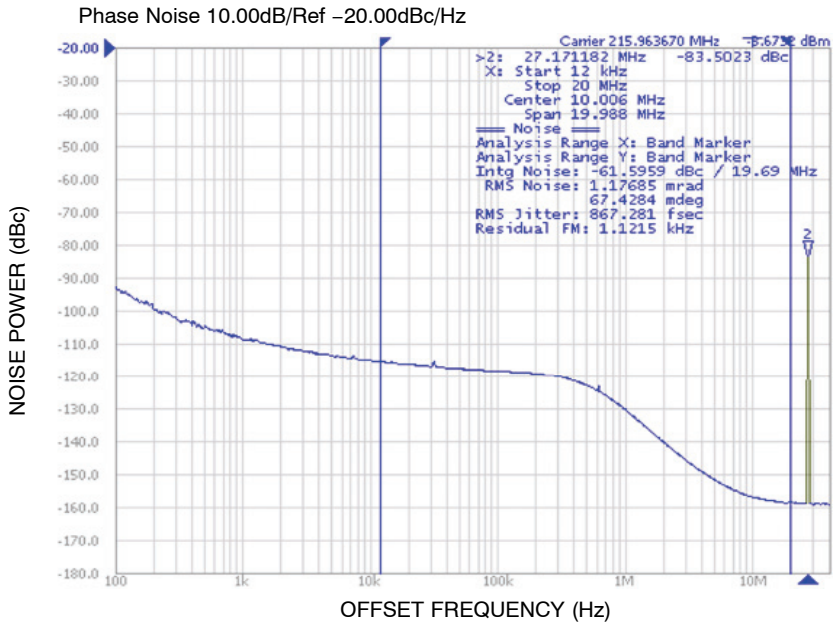


Figure 3. Typical Phase Noise Plot (V_{DD} = 3.3 V, V_{IN} = 0 V; Room Temperature)

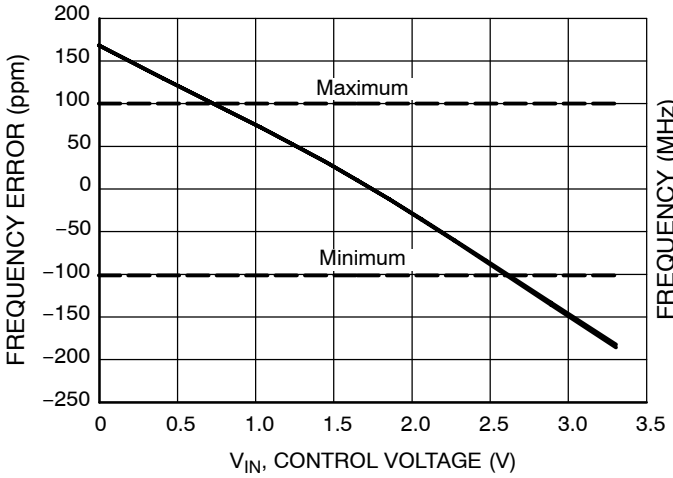


Figure 4. VCXO Pulling Range

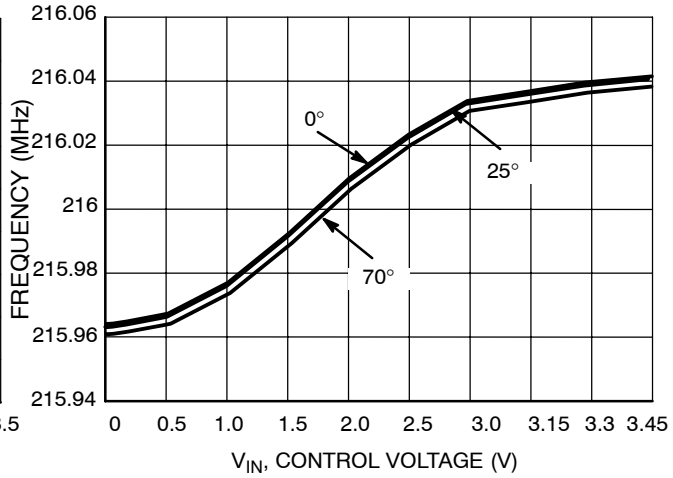


Figure 5. Output Clock Frequency vs. V_{IN} and Temperature

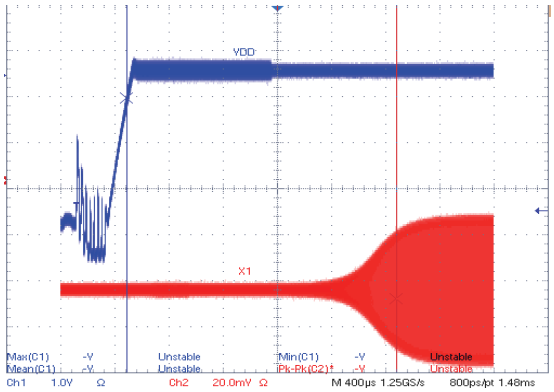


Figure 6. Typical Crystal Startup Time with V_{IN} = 0 V at Ambient Temperature (1.99 ms)

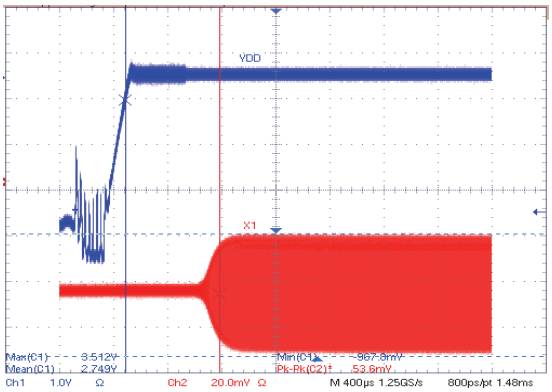


Figure 7. Typical Crystal Startup Time with V_{IN} = 3.3 V at Ambient Temperature (694 µs)

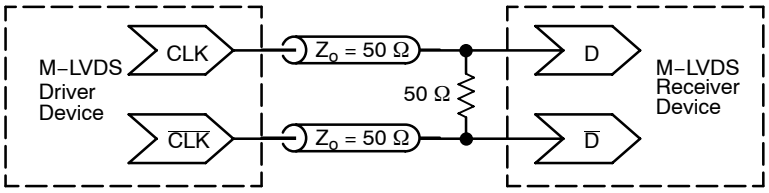


Figure 8. Typical Termination for Output Driver and Device Evaluation

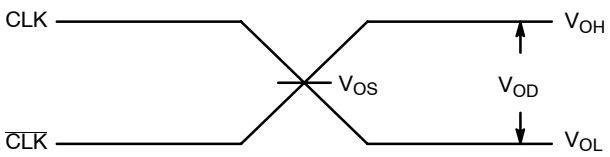


Figure 9. H−LVDS Output

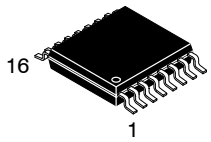
ORDERING INFORMATION

Device	Package	Shipping†
NB3N508SDTG	TSSOP−16 (Pb−Free)	96 Units / Rail
NB3N508SDTR2G	TSSOP−16 (Pb−Free)	2500 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

MECHANICAL CASE OUTLINE
PACKAGE DIMENSIONS

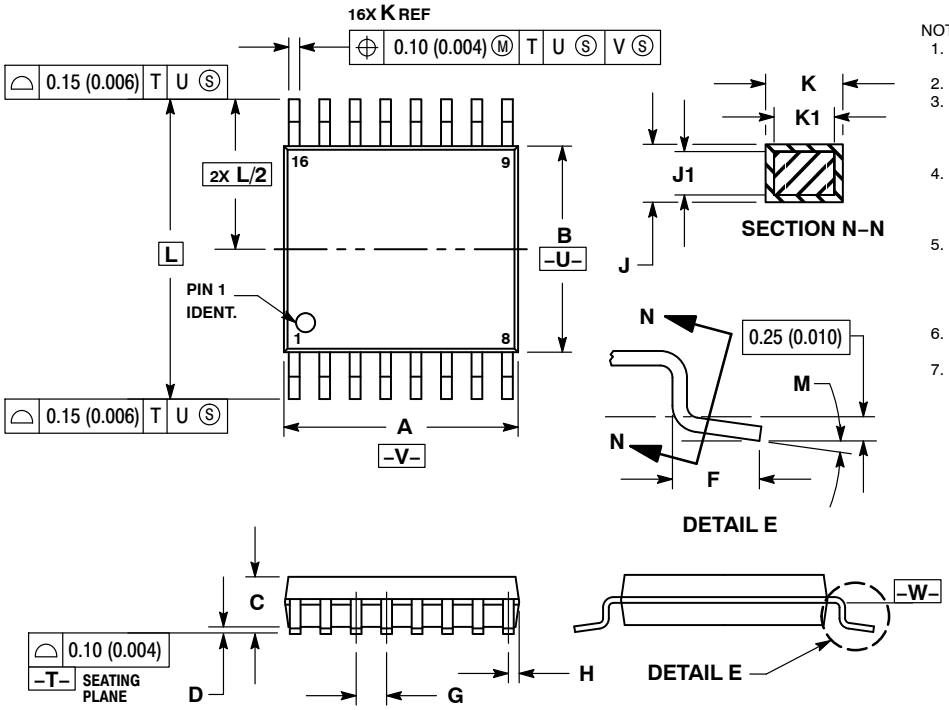
ON Semiconductor®



SCALE 2:1

TSSOP−16
CASE 948F−01
ISSUE B

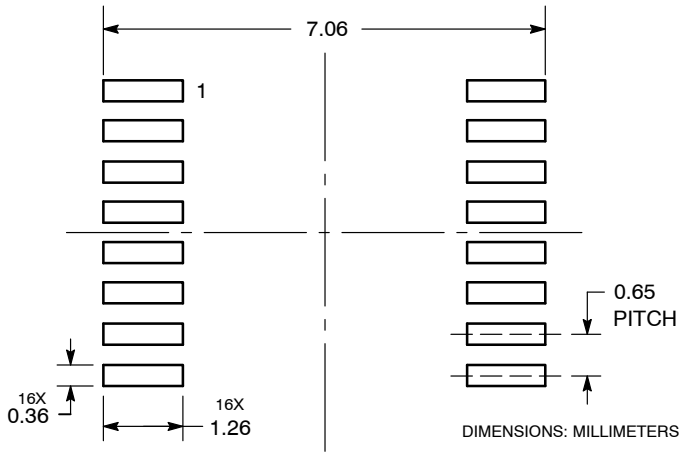
DATE 19 OCT 2006



NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSION A DOES NOT INCLUDE MOLD FLASH. PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
4. DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.
5. DIMENSION K DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE K DIMENSION AT MAXIMUM MATERIAL CONDITION.
6. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
7. DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE −W−.

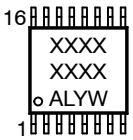
	MILLIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
A	4.90	5.10	0.193	0.200
B	4.30	4.50	0.169	0.177
C	−−−	1.20	−−−	0.047
D	0.05	0.15	0.002	0.006
F	0.50	0.75	0.020	0.030
G	0.65 BSC		0.026 BSC	
H	0.18	0.28	0.007	0.011
J	0.09	0.20	0.004	0.008
J1	0.09	0.16	0.004	0.006
K	0.19	0.30	0.007	0.012
K1	0.19	0.25	0.007	0.010
L	6.40 BSC		0.252 BSC	
M	0 °	8 °	0 °	8 °

SOLDERING FOOTPRINT



DIMENSIONS: MILLIMETERS

GENERIC MARKING DIAGRAM*



XXXX	= Specific Device Code
A	= Assembly Location
L	= Wafer Lot
Y	= Year
W	= Work Week
G or ▪	= Pb−Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb−Free indicator, “G” or microdot “ ▪”, may or may not be present.

DOCUMENT NUMBER:	98ASH70247A	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped “CONTROLLED COPY” in red.
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